

# Ignition Gate Drive IC FAD1110-F085

#### Description

The FAD1110F085 is designed to directly drive an ignition IGBT and control the current and spark event of the coil. The coil current is controlledvia the input pin. When the differential input is driven high, the output of the FAD1110F085 is enabled to turn on the IGBT and start charging the coil.

An input spike filtersuppresses differentialinput signals of less then 13 s in duration. A Max Dwell timer is included in the FAD1110ïF085which will turn off the IGBT if the input stays active for longer than the programmed time. This time interval can be modified through an external capacito/then the Max Dwell timer is exceeded, the FAD111ïF085 will enter a HariöShutiDown mode (HSD) and turn off the IGBT immediately. The FAD11ïF0085 will also limit the collector current of the IGBT to during charging. This again is done through the sense resistor in the emitter leg of the Ignition IGBT developing a signal input to the Land of the FAD1110ïF085.

#### **Features**

- € Differential Input for Ground Shift Disturbances Suppression
- € Signal Line Input Buffer
- € Input Spike Filter
- € Operation from Ignition or Battery Line
- € Ground Shift Tolerance 2 V to 3 V
- € Programmable Maximum Dwell Time
- € Control IGBT Current Limiting through §ENSEPin
- € Hard Shutdown Following Max Dwell Time Out
- € This is a PbFree Device

## **Applications**

The FAD1110F085 is anadvanced Ignition IGBT control IC available in a SO8 package or die sales. This full featured Smart Ignition IGBT Driver is particularly advantageous in "switch on coil" applications where size and system performance of the ignition driver are important.

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# ORDERING INFORMATION

Part Number	Operating Temperature Range	Package	Shipping †
FAD1110 ïF085	ï40°C to 150°C	8 ïSOIC	2500 units / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

# Recommended External Components

#### TYPICAL EXTERNAL COMPONENTS

Component	Description	Vendor	Parameter	Тур.	Unit
R <sub>BAT</sub>	Limits transient currents during load dump		R	200 to 300	
C <sub>BAT</sub>	Battery or Ignition voltage filtering		С	0.47	F
C <sub>BAT1</sub>	Battery noise transients		С	10	nF
CINC	•	•			

# Block Diagram

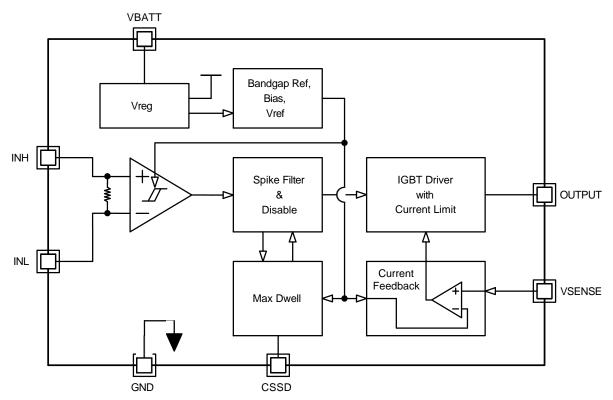


Figure 2. Block Diagram

# Package Outline

The FAD1110ïF085 is assembled in an 8 lead SOIC Package.

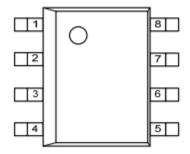


Figure 3. Pin Assignment (Top View)

# PIN DESCRIPTION

Name	Type	Description
Pin1	GND	Ground Reference of the Control IC
Pin2	INL	Input ground signal

#### RECOMMENDED OPERATING CONDITIONS (Reference Load Characteristics) (Note 1)

Symbol	Characteristic	Min.	Тур.	Max.	Units
I <sub>Ctyp</sub>	Collector (Coil) Operating Current		12		Α
L <sub>P</sub>	Coil Primary Inductance		1.5		mH
R <sub>P</sub>	Coil Primary Resistance (25°C)		0.4		
R <sub>LOAD</sub>	Load Resistance (for delay time measurements)		2		

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

#### ELECTRICAL CHARACTERISTICS

ELECTRICAL	. CHARACTERISTICS					
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
POWER SUPP	PLY CONDITIONS V <sub>BAT</sub> = 6 to 28 \	$I$ ; $T_J = "40$ °C to 150°C (unless otherwise specification)	ied)			
V <sub>BAT1</sub>	Operating voltage	Coil switching function	4		28	V
$V_{BAT2}$	Operating voltage	All functions	6		28	V
I <sub>BAT</sub>	Supply current	T <sub>J</sub> = 150 °C, V <sub>BAT</sub> = 28 V, Input = 5 V			4	mA
$V_{CLAMP}$	V <sub>BATTERY</sub> clamp	I <sub>BATT</sub> = 10 mA	33		40	V
SENSE PIN C	ONDITIONS $V_{BAT} = 6 \text{ to } 28 \text{ V}$ ; $T_J =$	= ï40°C to 150 °C (unless otherwise specified)				
$V_{LIMIT}$	Sense Voltage at current limit		200	220	240	mV
T <sub>SPIKE</sub>	Input spike filter	Delay on rising and falling edge of Input		13		s
T <sub>D1</sub>	Turn on delay time	(Time from Input = 4.0 V to V <sub>OUT</sub> = 4.0 V)		17		s
T <sub>D2</sub>	Turn off delay time	(Time from Input = 0.5 V to $V_{C \bar{i}GND} = 1.0 \text{ V}$ )		17		S
INPUT CONTE	ROL CONDITIONS V <sub>BAT</sub> = 6 to 28	V; T <sub>J</sub> = ï40°C to + 150°C (unless otherwise spec	cified)			
V <sub>INLD</sub>	Differential Input low voltage	INL = GND	1.3	1.7	2.1	V
V <sub>INHD</sub>	Differential Input high voltage	INL = GND	1.7	2.2	2.7	V
$V_{INHys}$	Input voltage hysteresis		0.25	0.5	0.75	V
I <sub>IN</sub>	Input current	V <sub>BAT</sub> = 0 V, INL = GND		0.10xV <sub>INH</sub>		mA
I <sub>IN</sub>	Input current	6 V < V <sub>BAT</sub> < 20 V, INL = GND		0.10xV <sub>INH</sub>		mA
V <sub>CM</sub>	Common mode voltage	Between V <sub>INH</sub> and V <sub>INL</sub> reference to GND	ï2		3	V
$V_{INHGF}$	Floating INH voltage	(6 V < $V_S$ < 20 $V_{INH}$ and INL floating) refer to GND @ T = 25°C		0.5		V
$V_{INLGF}$	Floating INL voltage	(6 V < $V_S$ < 20 $V_{INH}$ and INL floating) refer to GND @ T = 25°C		0.5		V
GATE OUTPU	T VOLTAGE MAX V <sub>BAT</sub> = 6 to 28 \	$T/T_J = "40°C \text{ to } 150°C \text{ (unless otherwise specification)}$	ed)			
$V_{GMAX}$	Vgate max	16 K pulldown resistor	4.5	5.4	6	V
$V_{GLOW}$	Vgate low	(0 mA < I <sub>GATE</sub> < 0.4 mA @ T = 25°C)	0.0		0.4	V
DIAGNOSTIC	FUNCTIONS AND PROTECTION	$V_{BAT} = 6$ to 28 V; $T_J = \ddot{4}0^{\circ}$ C to 150°C (unless	otherwise	e specified)		
CSSD <sub>MIN</sub>	Minimum dwell time capacitor			5		nF
TD <sub>MAX</sub>	Maximum dwell time	(CSSD = 50 nF)	65	100	135	ms
I <sub>CSSD1</sub>	CSSD Pin current for TDMAX		0.75	1.0	1.25	Α
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Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

<sup>1.</sup> onsemi does not recommend exceeding them or designing to Absolute Maximum Ratings. ( ï40°C to 150°C unless otherwise stated)

### TYPICAL PERFORMANCE CHARACTERISTICS

Input and Spike Filter

Maximum Dwell Time and Hard iShutdown (HSD) When

When the differential input signal voltage between INH and INL pins reaches NHD, the IGBT will be switched on charging the coil. When this differential input voltage goes below VINLD, the coil current through the IGBT will be turned off. Positive and negative spikes of less thank duration athe input line will be filtered out and will not turn on/off the IGBT.

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